

DUAL N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Features

- Dual N-Channel MOSFET
- Low On-Resistance
- Very Low Gate Threshold Voltage (1.0V Max)
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Small Surface Mount Package
- ESD Protected up to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

Mechanical Data

- Package: SOT26
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (@3)
- Weight: 0.015 grams (Approximate)



Part Number	Poolkage	Packing		
Fait Nulliber	Package	Qty.	Carrier	
DMN5L06DMK-7	SOT26	3000	Tape & Reel	

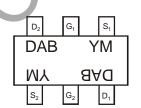
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

See https: Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



DAB = Product Type Marking Code YM = Date Code Marking Y = Year (ex: J = 2022) M = Month (ex: 9 = September)

Date Code Key

Year	2006		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	Т		J	K	L	М	Ν	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Cha	racteristic	Symbol	Value	Unit
Drain Source Voltage		Vdss	50	V
Gate-Source Voltage		Vgss	±20	V
Drain Current (Note 5)	Continuous Pulsed (Note 6)	lD	305 800	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	400	mW
Thermal Resistance, Junction to Ambient	Reja	313	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-65 to +150	٦°

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

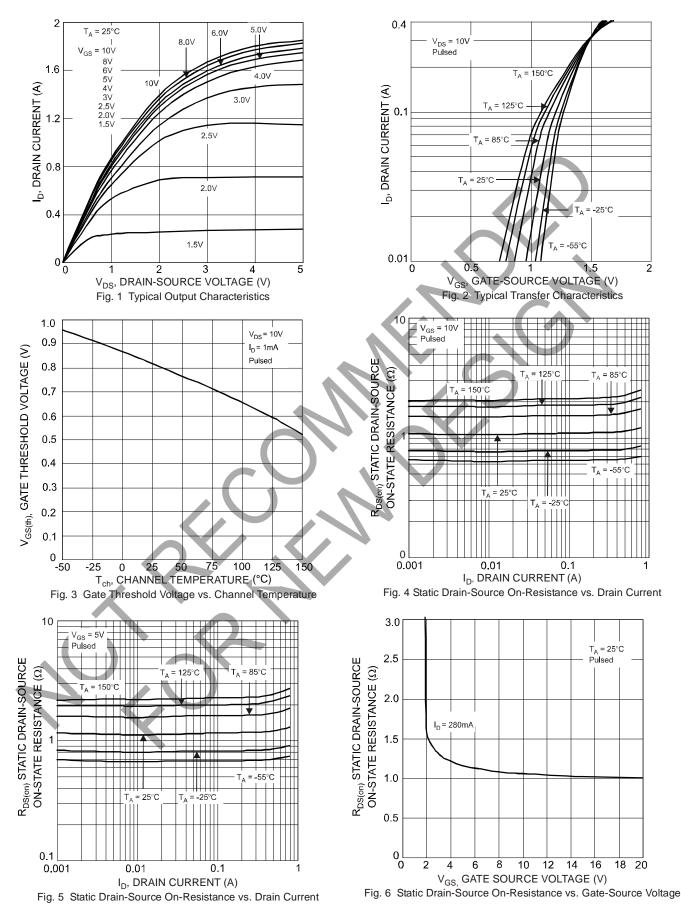
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BVDSS	50	—		V	$V_{GS} = 0V, I_D = 10\mu A$
Zero Gate Voltage Drain Current @ T _C = +2	5°C IDSS			60	nA	$V_{DS} = 50V, V_{GS} = 0V$
Gate-Body Leakage	lgss	1		1 500 50	μA nA nA	$V_{GS} = \pm 12V, V_{DS} = 0V$ $V_{GS} = \pm 10V, V_{DS} = 0V$ $V_{GS} = \pm 5V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(th)	0.49	-	1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance	R _{DS(on)}			3.0 2.5 2.0	Ω	$V_{GS} = 1.8V, I_D = 50mA$ $V_{GS} = 2.5V, I_D = 50mA$ $V_{GS} = 5.0V, I_D = 50mA$
On-State Drain Current	ID(ON)	0.5	1.4		А	V _{GS} = 10V, V _{DS} = 7.5V
Forward Transconductance	Y _{fs}	200	—	_	mS	V _{DS} = 10V, I _D = 0.2A
Source-Drain Diode Forward Voltage	Vsd	0.5	_	1.4	V	Vgs = 0V, Is = 115mA
DYNAMIC CHARACTERISTICS	\mathbf{X}					
Input Capacitance	Ciss	_	—	50	pF	
Output Capacitance	Coss	_	_	25	pF	V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	_	5.0	pF	1 - 1.00012

Notes:

5. Device mounted on FR-4 PCB.
6. Pulse width ≤ 10µs, Duty Cycle ≤ 1%.
7. Short duration pulse test used to minimize self-heating effect.

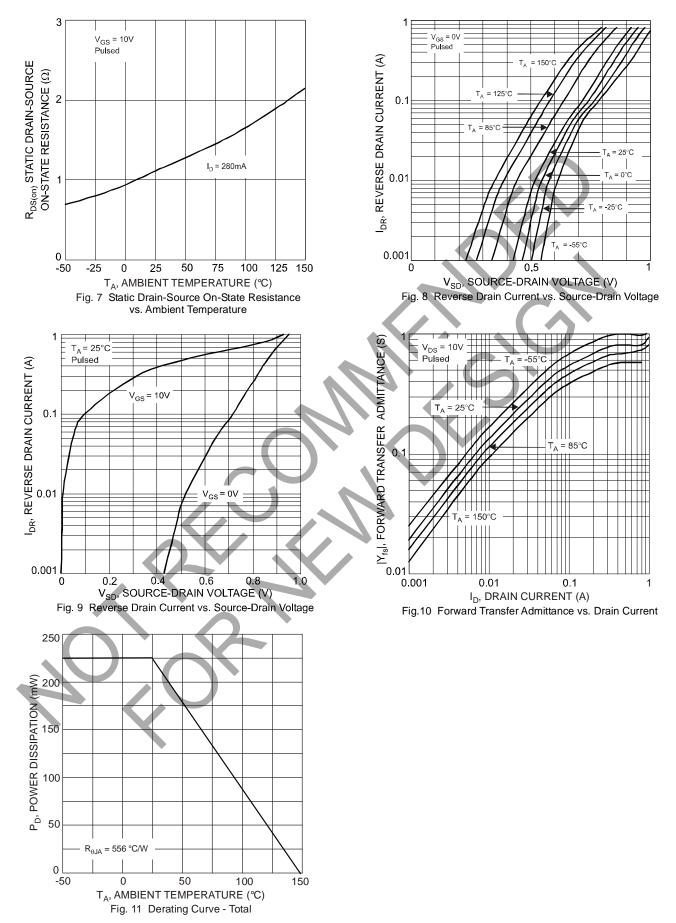


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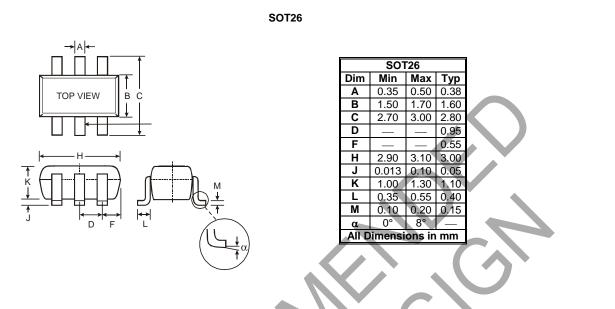
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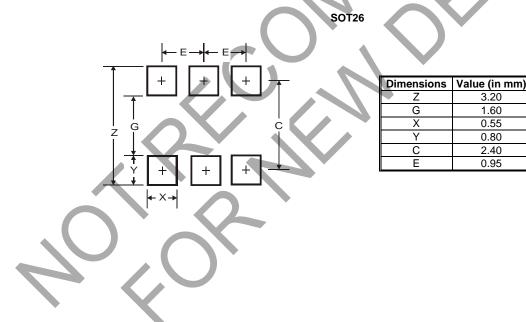
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.





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